SECOS
Elektronische Bauelemente

SBL20A60
60V, 20A
Low VF Planar MOS Barrier Schottky Rectifiers

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

FEATURES
- Planar MOS Schottky technology
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

MECHANICAL DATA
- Case: Molded plastic
- Epoxy: UL94V-0 rate flame retardant
- Lead: Lead solderable per MIL-STD-202 method 208 guaranteed
- Polarity: As Marked
- Mounting position: Any

TO-220

ORDER INFORMATION

Part Number	Type
SBL20A60	Lead (Pb)-free
SBL20A60-C	Lead (Pb)-free and Halogen-free
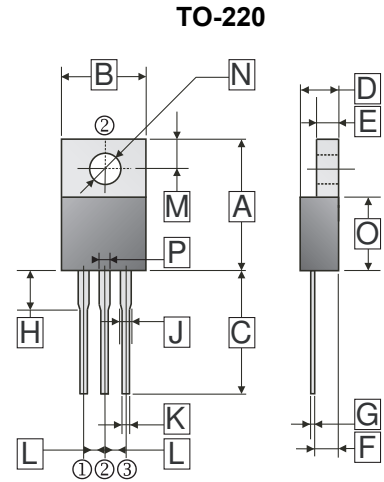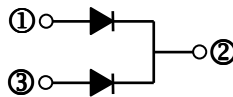
REF.	Millimeter Min.	Millimeter Max.	REF.	Millimeter Min.	Millimeter Max.
A	14.22	16.51	J	0.70	1.78
B	9.57	10.90	K	0.38	1.11
C	12.50	14.75	L	2.01	3.07
D	3.56	5.10	M	2.22	3.43
E	0.51	1.47	N	3.10	4.31
F	2.03	3.19	O	8.10	9.65
G	0.279	0.76	P	1.18 Typ.	
H	2.95	4.5			

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Rating 25°C ambient temperature unless otherwise specified. Single phase half wave, 60Hz, resistive or inductive load. For capacitive load, de-rate current by 20%.)

| Parameter		Symbol	Rating	Unit
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	60	V
Working Peak Reverse Voltage		V_{RSM}	60	V
Maximum DC Blocking Voltage		V_{DC}	60	V
Maximum Average Forward Rectified Current	(Per Leg)	I_F	10	A
	(Per Device)		20	
Peak Forward Surge Current, 8.3 ms single half sine-wave Superimposed on rated load (JEDEC method)		I_{FSM}	120	A
Voltage Rate of Chance (Rated V_R)		dv/dt	10000	V / µs
Typical Thermal Resistance from Junction to Case		$R_{\theta JC}$	2	°C /W
Operating and Storage Temperature Range		T_J, T_{STG}	150,-55~150	°C

ELECTRICAL CHARACTERISTICS

| Parameter	Symbol	Typ.	Max.	Unit	Test Condition
Maximum Instantaneous Forward Voltage	V_F	0.45	0.49	V	I_F=3A, T_J=25°C
		0.5	0.55		I_F=5A, T_J=25°C
		0.6	0.65		I_F=10A, T_J=25°C
		0.57	-		I_F=10A, T_J=125°C
Maximum DC Reverse Current at Rated DC Blocking Voltage [2]	I_R	-	0.5	mA	T_J=25°C
		-	20		T_J=100°C
Typical Junction Capacitance [1]	C_J	280	-	pF	

Notes:
1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.
2. Pulse Test：Pulse Width = 300 µs, Duty Cycle ≦ 2.0%.

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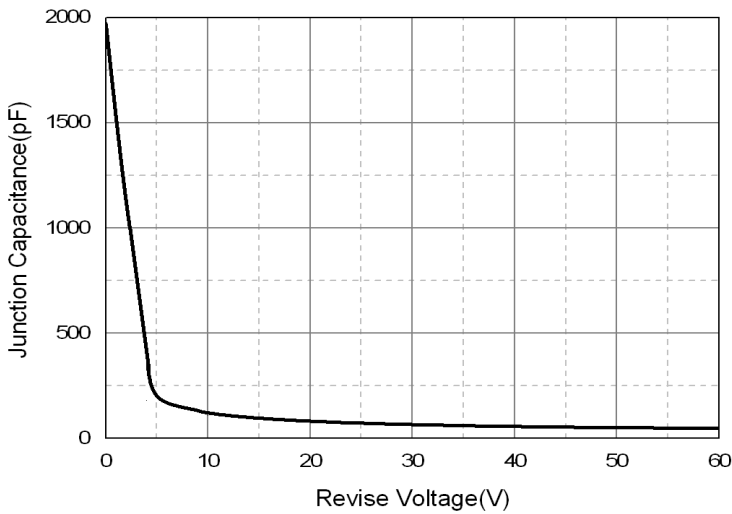
RATINGS AND CHARACTERISTIC CURVES

Typical Forward Current Derating Curve
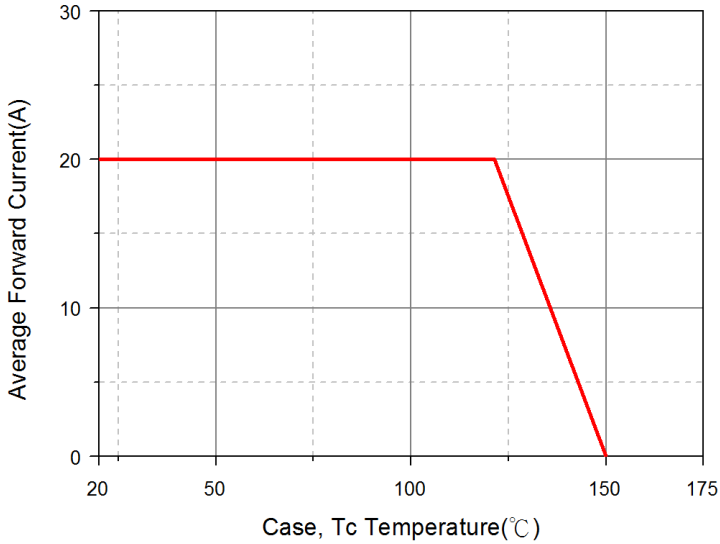
Typical Forward Characteristic
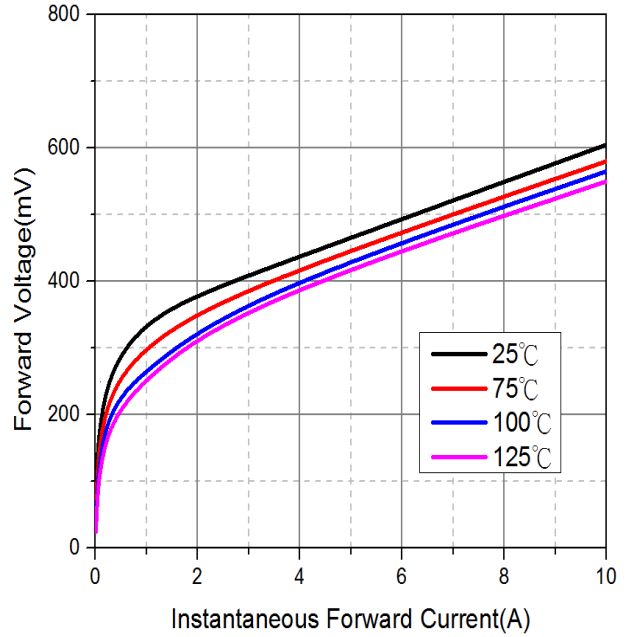
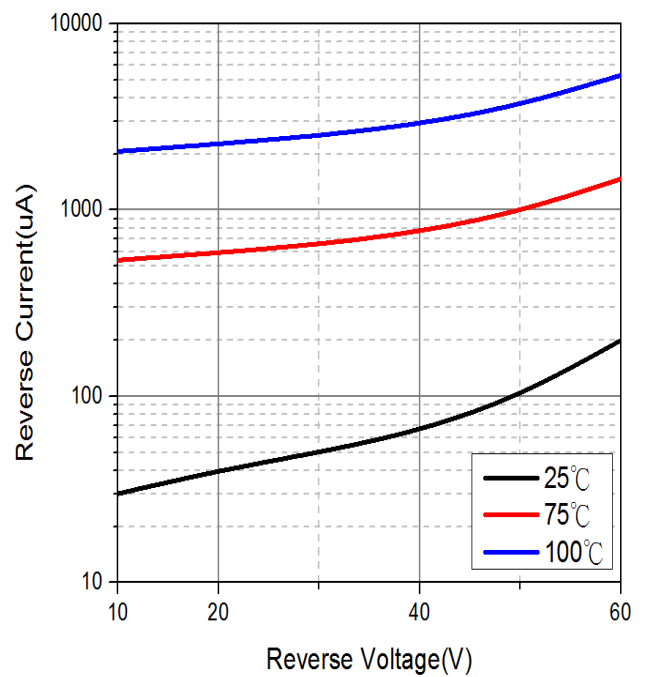### Typical Junction Capacitance

Typical Reverse Characteristic

Maximum Non-Repetitive Forward Surge Current